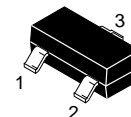
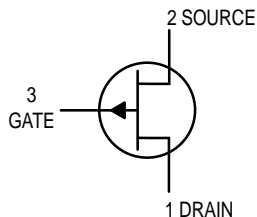


# JFET General Purpose Transistor

## P-Channel

**MMBF5460LT1**



CASE 318-08, STYLE 10  
SOT-23 (TO-236AB)

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Gate Voltage	$V_{DG}$	40	Vdc
Reverse Gate-Source Voltage	$V_{GSR}$	40	Vdc
Forward Gate Current	$I_{GF}$	10	mAdc

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board <sup>(1)</sup> $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

### DEVICE MARKING

MMBF5460LT1 = 6E

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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### OFF CHARACTERISTICS

Gate-Source Breakdown Voltage ( $I_G = 10 \mu\text{Adc}$ , $V_{DS} = 0$ )	$V_{(BR)GSS}$	40	—	—	Vdc
Gate Reverse Current ( $V_{GS} = 20 \text{Vdc}$ , $V_{DS} = 0$ ) ( $V_{GS} = 20 \text{Vdc}$ , $V_{DS} = 0$ , $T_A = 100^\circ\text{C}$ )	$I_{GSS}$	— —	— —	5.0 1.0	nAdc $\mu\text{Adc}$
Gate Source Cutoff Voltage ( $V_{DS} = 15 \text{Vdc}$ , $I_D = 1.0 \mu\text{Adc}$ )	$V_{GS(off)}$	0.75	—	6.0	Vdc
Gate Source Voltage ( $V_{DS} = 15 \text{Vdc}$ , $I_D = 0.1 \text{mAdc}$ )	$V_{GS}$	0.5	—	4.0	Vdc

### ON CHARACTERISTICS

Zero-Gate-Voltage Drain Current ( $V_{DS} = 15 \text{Vdc}$ , $V_{GS} = 0$ )	$I_{DSS}$	-1.0	—	-5.0	mAdc
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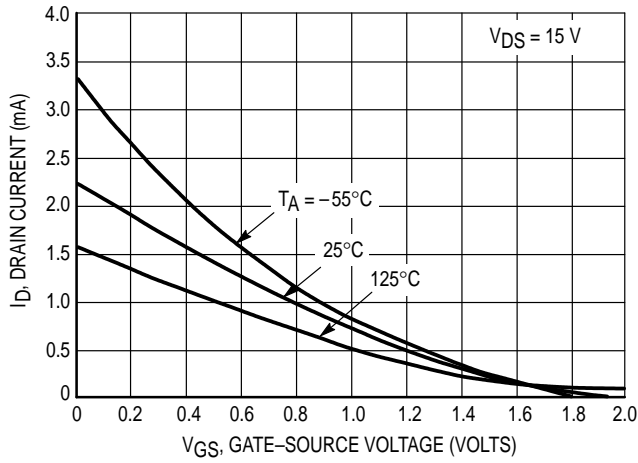
### SMALL-SIGNAL CHARACTERISTICS

Forward Transfer Admittance ( $V_{DS} = 15 \text{Vdc}$ , $V_{GS} = 0$ , $f = 1.0 \text{kHz}$ )	$ Y_{fs} $	1000	—	4000	$\mu\text{mhos}$
Output Admittance ( $V_{DS} = 15 \text{Vdc}$ , $V_{GS} = 0$ , $f = 1.0 \text{kHz}$ )	$ y_{os} $	—	—	75	$\mu\text{mhos}$
Input Capacitance ( $V_{DS} = 15 \text{Vdc}$ , $V_{GS} = 0$ , $f = 1.0 \text{MHz}$ )	$C_{iss}$	—	5.0	7.0	pF
Reverse Transfer Capacitance ( $V_{DS} = 15 \text{Vdc}$ , $V_{GS} = 0$ , $f = 1.0 \text{MHz}$ )	$C_{rss}$	—	1.0	2.0	pF
Equivalent Short-Circuit Input Noise Voltage ( $V_{DS} = 15 \text{Vdc}$ , $V_{GS} = 0$ , $R_G = 1.0 \text{M}\Omega$ , $f = 100 \text{Hz}$ , $\text{BW} = 1.0 \text{Hz}$ )	$e_n$	—	20	—	$\text{nV}/\sqrt{\text{Hz}}$

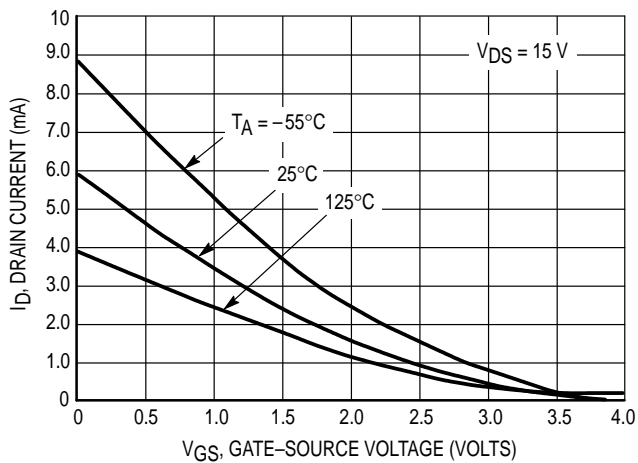
1. FR-5 =  $1.0 \times 0.75 \times 0.062 \text{ in.}$

Thermal Clad is a trademark of the Bergquist Company

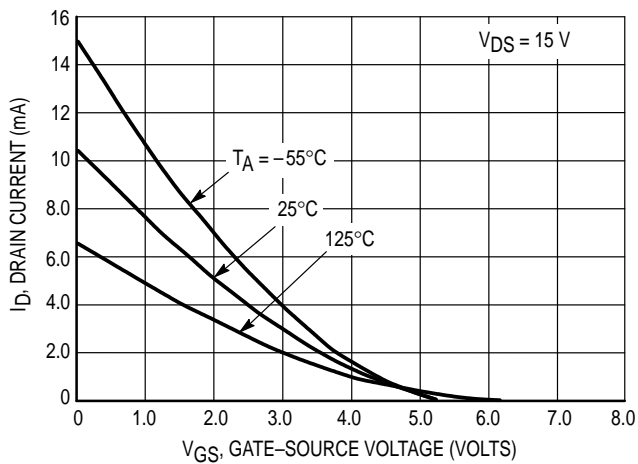
**DRAIN CURRENT versus GATE SOURCE VOLTAGE**



**Figure 1.  $V_{GS(off)} = 2.0$  Volts**

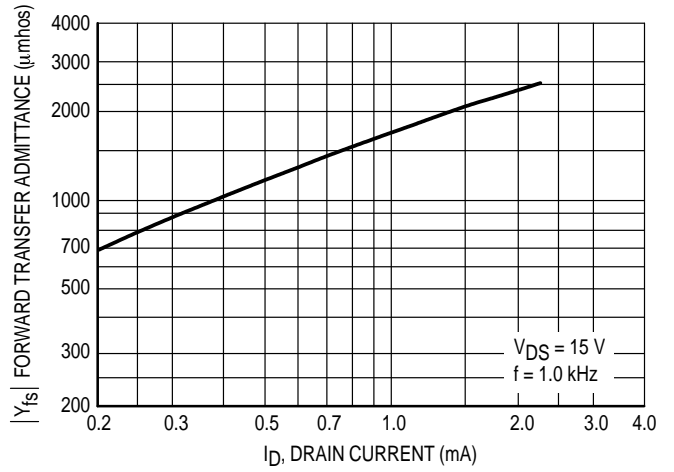


**Figure 2.  $V_{GS(off)} = 4.0$  Volts**

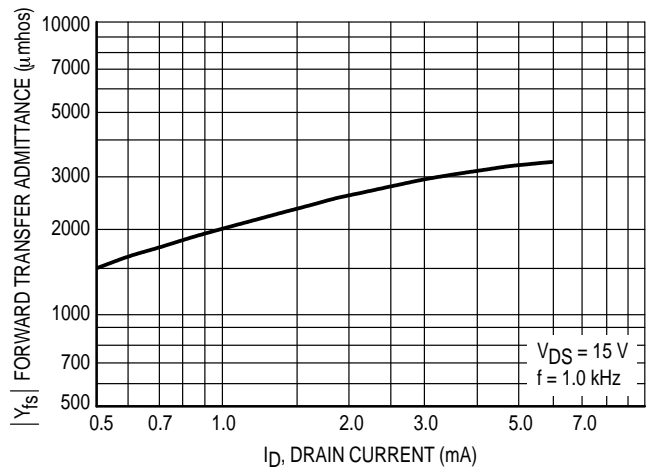


**Figure 3.  $V_{GS(off)} = 5.0$  Volts**

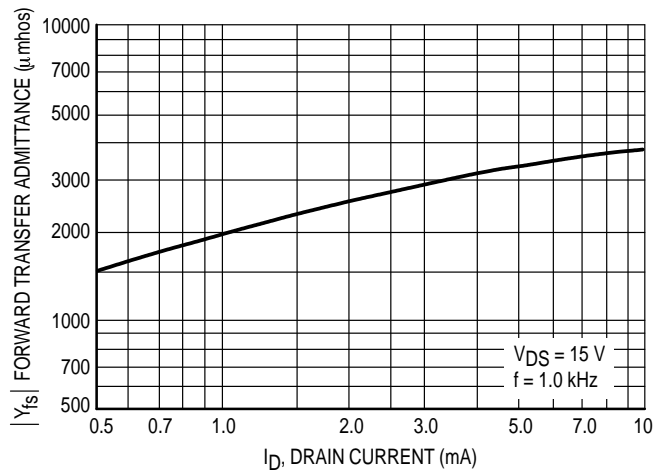
**FORWARD TRANSFER ADMITTANCE versus DRAIN CURRENT**



**Figure 4.  $V_{GS(off)} = 2.0$  Volts**



**Figure 5.  $V_{GS(off)} = 4.0$  Volts**



**Figure 6.  $V_{GS(off)} = 5.0$  Volts**

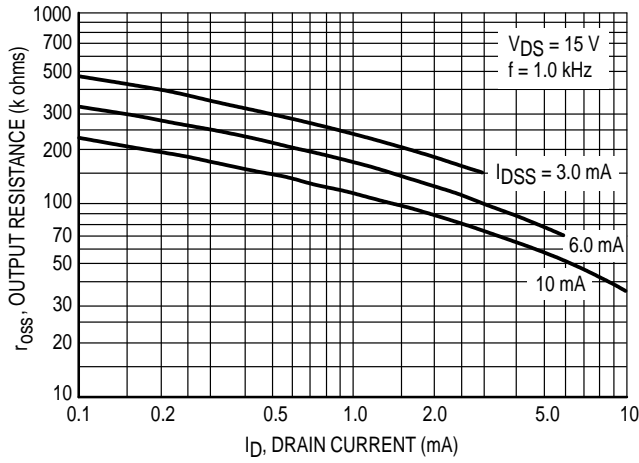


Figure 7. Output Resistance versus Drain Current

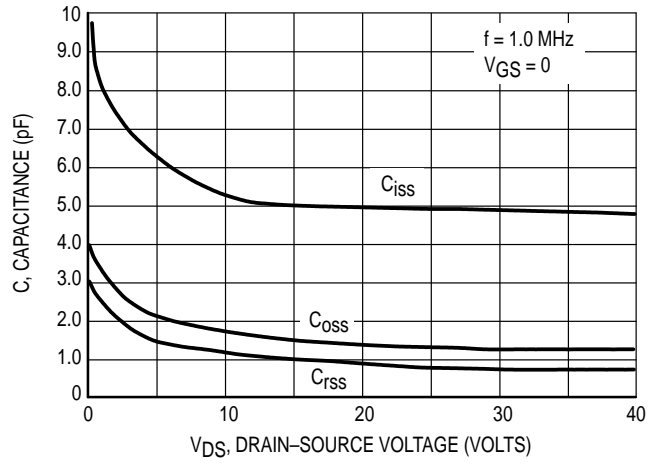


Figure 8. Capacitance versus Drain-Source Voltage

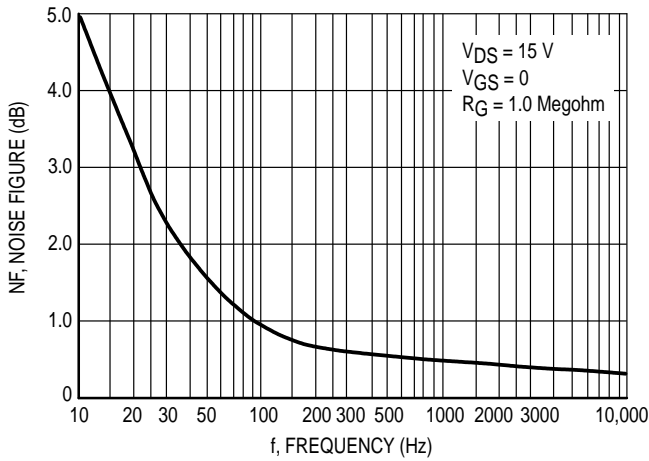


Figure 9. Noise Figure versus Frequency

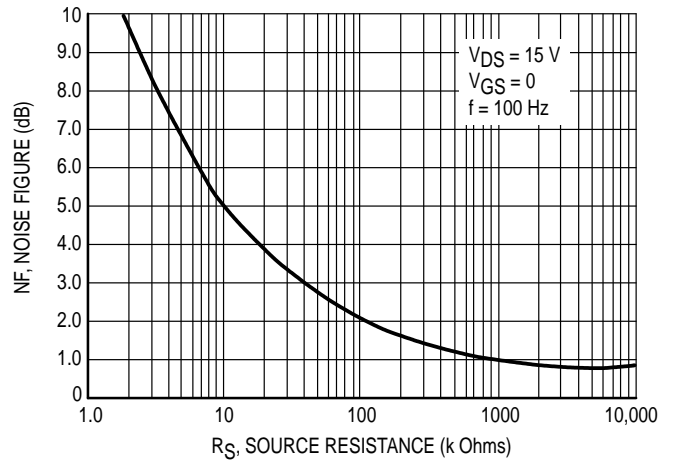
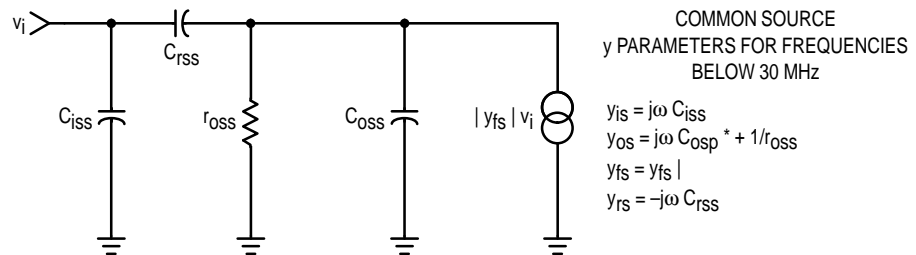


Figure 10. Noise Figure versus Source Resistance



COMMON SOURCE  
y PARAMETERS FOR FREQUENCIES  
BELOW 30 MHz

$$y_{is} = j\omega C_{iss}$$

$$y_{os} = j\omega C_{osp} + 1/r_{oss}$$

$$y_{fs} = y_{fs}$$

$$y_{rs} = -j\omega C_{rss}$$

\*  $C_{osp}$  is  $C_{oss}$  in parallel with Series Combination of  $C_{iss}$  and  $C_{rss}$ .

NOTE:

- Graphical data is presented for dc conditions. Tabular data is given for pulsed conditions (Pulse Width = 630 ms, Duty Cycle = 10%).

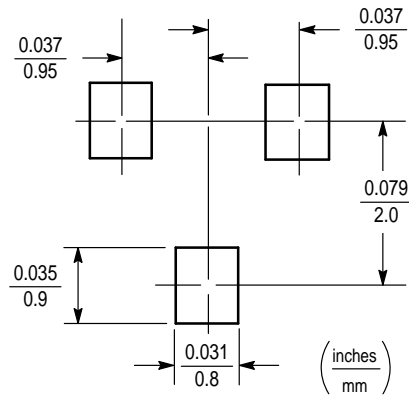
Figure 11. Equivalent Low Frequency Circuit

## INFORMATION FOR USING THE SOT-23 SURFACE MOUNT PACKAGE

### MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



**SOT-23**

### SOT-23 POWER DISSIPATION

The power dissipation of the SOT-23 is a function of the pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by  $T_{J(max)}$ , the maximum rated junction temperature of the die,  $R_{\theta JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature,  $T_A$ . Using the values provided on the data sheet for the SOT-23 package,  $P_D$  can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature  $T_A$  of 25°C, one can calculate the power dissipation of the device which in this case is 225 milliwatts.

$$P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{556^\circ\text{C/W}} = 225 \text{ milliwatts}$$

The 556°C/W for the SOT-23 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 225 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-23 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

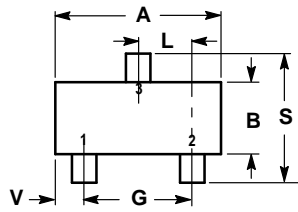
### SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

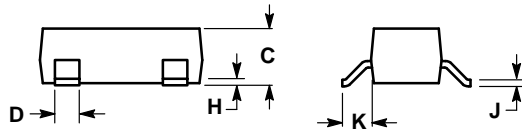
- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.

\* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

PACKAGE DIMENSIONS



STYLE 10:  
 PIN 1. DRAIN  
 2. SOURCE  
 3. GATE



- NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: INCH.  
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0180	0.0236	0.45	0.60
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.0984	2.10	2.50
V	0.0177	0.0236	0.45	0.60

**CASE 318-08  
 ISSUE AE  
 SOT-23 (TO-236AB)**

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